**Metamaterial Thermoelectric Conversion**

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**Abstract:** We propose a thermoelectric device that can produce a thermal gradient even in a uniform-temperature environment. We introduced a metamaterial absorber (MA), which comprised a transparent calcium fluoride layer sandwiched between a silver mirror layer and silver microdisk arrays, at the one-end of a thermoelectric device made of bismuth antimony telluride. The heating efficiencies of the MA and opposite electrodes of the device were unbalanced, which induced the Seebeck effect and resulted in electricity generation. We fabricated the MA on a copper electrode loaded on a thermoelectric device and the device was placed it in a uniform temperature environment at 364 K. The 0.14 K thermal gradient across the device and the electric power density of 0.04 µW/cm² were experimentally measured.
Thermoelectric devices convert thermal energy into electricity; they can therefore be used to recover waste heat and convert it into a usable energy resource (1-3). The Seebeck effect can play a main role in thermoelectric conversion, in which the amplitude of the temperature gradient across a thermoelectric device is the key to determine the electric voltage generated across it. Since the Seebeck effect converts the temperature gradient across a thermoelectric device to the electric voltage, such devices have usually been installed only at the location where the large thermal gradients can be expected such as space probes, wearable electronics, and so on, and the installation sites for conventional thermoelectric devices are strongly limited (4). Although the Seebeck effect cannot be used under a uniform temperature environment, there are a lot of such places like as in water, on the road, inside the furnace, etc. Hence, conventional thermoelectric devices employ techniques to maintain an initial temperature gradient, for example, the cooling systems or pyramid-shape thermoelectric legs that leads to maintain thermal gradients (5, 6). However, these techniques cannot be practical solutions because such techniques just maintain an initial thermal gradient and lead to an increase in power generation cost. Therefore, new techniques that can create temperature gradients even though the device are surrounded by uniform temperature environments are strongly demanded and such technologies can dramatically expand the installation sites for the thermoelectric devices contributing to the energy recycling and energy-saving society.

In this paper, we propose a thermoelectric device loaded with the metamaterial absorber at the surface of its one end. Using large difference of the absorptivity between the device edges produced by metamaterial absorber, the device creates a temperature gradient even it is basked in the uniform and isotropic thermal radiations.

The metamaterial is an artificial material that exhibits extraordinary interaction with electromagnetic waves. There are tremendous number of reports about metamaterials that absorb electromagnetic waves from the visible light region to the infrared region in which thermal radiation is involved (7). A metamaterial also works as a transducer that converts the absorbed energy into local heating (8-11), and this local heating are successfully utilized as thermal therapy, photodetection, crystal growth, and energy conversion (12-15). We previously proposed to utilize this local heating as a metamaterial thermoelectric conversion scheme (16) and numerically predicted that a power density of 1.09 mW/cm² could be obtained under a uniform-temperature environment at 500 K. Our proposal can break the mold that thermoelectric conversion cannot occur under a uniform temperature environment. However, to date, effective thermoelectric signal generation within uniform temperature environment has not yet been realized because it is beyond the principle of conventional thermoelectric conversion. The experimental demonstration of a metamaterial thermoelectric conversion will increase the installation sites for thermoelectric conversion.

Here, we demonstrate a metamaterial thermoelectric conversion technique that generates electricity by extracting thermal energies from the surrounding medium without adopting cooling systems and discuss the driving mechanism. We attached metamaterial arrays to a copper electrode in contact with a thermoelectric device to design a thermal distribution across the device. The local heating generated on the metamaterial propagates to the underlying thermoelectric material via the copper electrode, resulting in an additional thermal gradient to drive thermoelectric generation under a uniform-temperature medium. Thus, we designed thermal distributions across a thermoelectric device by controlling the absorption properties of each surface of the device.
Unlike conventional thermoelectric devices, thermoelectric devices fabricated using the metamaterials can collect and extract thermal energies from the surrounding medium. Thus, these devices will pave the way to recover waste heat existing in the medium, such as air and water.

A metamaterial absorber (MA) consisting of a 150 nm thick silver (Ag) film and a 100 nm thick Ag disk array sandwiching a 60 nm thick calcium fluoride (CaF$_2$) layer was fabricated on a 300 µm thick copper plate (electrode) by a nanofabrication process (Figure 1(A)). The copper electrode area was 4 × 6 mm$^2$. The diameter and pitch of the Ag disk were 1.8 and 3.0 µm, respectively (Figure 1(B)). These parameters of the MA were employed to achieve an absorption peak at a wavelength of 6 µm, which overlaps with the blackbody radiation spectrum at 364 K (91 °C). The MA arrays were fabricated at the center of the copper electrode with an area of 2.1 × 2.1 mm$^2$.

Figure 1(C) shows a comparison of the calculated and measured absorption spectra of MA and a blackbody radiation at 364 K. The absorption spectra were calculated using the 1 - reflectance. The measured and calculated absorption spectrum of the MA showed good consistency, indicating that the MAs were fabricated as designed. The measured absorption spectrum shows a resonance peak at 6.08 µm attributed to its magnetic resonance mode (17), indicating that the MA arrays absorb a part of the thermal radiation emitted from the surrounding medium at 364 K and convert the absorbed energy into local heating.

**Fig. 1.** (A) Schematic of MA arrays fabricated on a copper electrode. (B) A top-view scanning electron microscope (SEM) image of MA arrays. The inset is a magnified image, and the scale bars in the low and high magnified images represent 30 and 3 µm, respectively. (C) Comparison of the measured (red) and calculated (black) absorption spectra of the MA, a measured
absorption spectrum of the control electrode (dashed black), and a calculated blackbody radiation spectrum (blue) at 364 K.

The MA-fabricated-copper electrode was attached to both the edges of a p-type bismuth antimony telluride (Bi$_{0.3}$Sb$_{1.7}$Te$_3$) using a soldering paste, to obtain the thermoelectric device. Bi$_{0.3}$Sb$_{1.7}$Te$_3$ element was utilized in this research since this material shows good thermoelectric performance. The cross-sectional area and length of the Bi$_{0.3}$Sb$_{1.7}$Te$_3$ element were 1 × 2 mm$^2$ and 8.8 mm, respectively, and were provided by TOSHIMA Manufacturing Co., Ltd. A control electrode was attached to the opposite edge of the thermoelectric device. The control electrode consisted of 60 nm thick CaF$_2$ and 150 nm thick Ag deposited on a copper electrode. The dashed line in Figure 1(C) is the measured absorption spectrum of the control electrode, indicating that the control electrode does not absorb thermal radiation. The difference between the MA and control electrode is the existence of the Ag disk on the CaF$_2$ and Ag layers in case of MA, meaning that we can control the absorption properties of the MA effectively by placing Ag disks on the top of the CaF$_2$ and Ag layers. For electrical connections, gold wires were connected to each copper electrode using Ag paste. We call the device loaded with the MA fabricated copper electrode as the MA thermoelectric device (Figure 2(A)). In addition, we prepared a control thermoelectric device loaded with control electrodes at both edges of Bi$_{0.3}$Sb$_{1.7}$Te$_3$ and called it a control device. To examine the effect of the MA electrode on the thermoelectric performance, we replaced the control electrode of the control device with the MA electrode to model the MA device, by retaining the Bi$_{0.3}$Sb$_{1.7}$Te$_3$ thermoelectric element of the control device; hence, the difference between the MA device and the control device is only an attachment of the electrode. This procedure clarified the effect of MA on the device performance because the Bi$_{0.3}$Sb$_{1.7}$Te$_3$ thermoelectric element was retained.

The MA thermoelectric device was placed in an electric furnace, and the output voltage generated across the MA thermoelectric device was measured. The convection created by the furnace fan winds influenced the thermoelectric performance since it will induce a transient thermal gradient across a thermoelectric device. To eliminate the convection effect on thermoelectric generation, the MA device was capped with a carbon pod with a diameter and height of 2.5 and 1.5 cm, respectively (Figure 2(B),(C)). We set two thermistors 2 mm away from the electrode surfaces of the thermoelectric device to monitor the environmental temperature in the vicinity of the electrodes. The thermistors were calibrated carefully to show the same temperature in the same temperature environment (see SI Materials and Methods, Figure S1). Figure S2 shows the time dependence of the output voltage generated across the MA thermoelectric device (red line) and the environmental temperatures measured by thermistors located in front of the left (dashed black line) and right (dashed blue line) electrodes of the MA device. The temperature graphs indicate that the environmental measured temperature inside the furnace reached an equilibrium approximately 60 min after the furnace was started and that the temperature difference between the thermistors placed in front of both electrodes was less than 0.2 K. The temperature difference between the left and right thermistors was less than ±0.2 K when the two thermistors were exposed to the same temperature (see SI Calibration of thermistors). Therefore, we concluded that the environmental temperature at the left and right thermistors is uniform if the temperature difference between the two thermistors is less than 0.2 K. The output voltage was almost constant after 120 min after the furnace was started heating, and we confirmed that the output voltage was stable until the furnace was stopped heating. We averaged the output
voltage from 10800 s (180 min) to 11400 s (190 min) after the furnace was started heating. Because the Bi\textsubscript{0.3}Sb\textsubscript{1.7}Te\textsubscript{3} element of the MA device was identical to that of the control device, output voltage measurements of these two devices were carried out, separately.

Figure 2(D) illustrates the dependence of the output voltage on the measured environmental temperatures. The values of output voltage generated across the MA and control device were 18.9 ± 6.7 µV and -1.2 ± 4.4 µV (number of the measured sample: 5), respectively, at the measured environmental temperature of 364 K. The output voltage generated across the MA device was significantly larger than that across the control device. Five readings of the output voltage and corresponding environmental temperatures inside the furnace were recorded and were represented by error bars. Furthermore, the output voltages were examined with several MA and control electrodes of several different thermoelectrical devices to calculate the average voltages, which indicated that these output voltages were highly reproducible. The output voltage generated across the MA device corresponded to an additional temperature gradient of 0.14 K estimated by the measured Seebeck coefficient of the p-type Bi\textsubscript{0.3}Sb\textsubscript{1.7}Te\textsubscript{3} element (140 µV/K).

In addition, the output voltages generated across these devices were measured at different environmental temperatures of 320, 342, 388, and 402 K (Figure 2(D)). Figure 2E shows a comparison between the measured absorption spectrum of MA and the calculated blackbody radiation spectra at those temperatures. The output voltages generated across the MA thermoelectric device showed significant temperature dependence, whereas those generated on the control device showed no temperature dependence. At every environmental temperature, the thermistors showed a maximum temperature difference of less than ±0.2 K, hence we concluded that the temperatures at the vicinities of the left and right electrodes were the same. Figures 2(D) and S3 show that the energy absorbed by the MA increases as the environmental temperature increases, indicating an increase in the amount of local heating.

Figure 2(E) shows a comparison between the additional temperature gradients estimated by the measured output voltages and the calculated power densities absorbed by the MA. We observed the additional temperature gradients to be the same as the local heat temperatures generated on the MA because almost all the local heating was transferred to the Bi\textsubscript{0.3}Sb\textsubscript{1.7}Te\textsubscript{3} thermoelectric element owing to the high thermal conductivity of the copper electrode. The absorbed power densities of the MA contributing to local heat generation, attributed to the magnetic resonance of MA, were calculated in the wavelength range of 4–10 µm. Figure 2(E) shows that the additional temperature gradients and absorbed power densities increase as the environmental temperature increases. This indicates that the additional temperature gradients created by the MA electrode originate from thermal radiation absorption by the MA.
Fig. 2. (A) Schematic of the Bi$_{0.3}$Sb$_{1.7}$Te$_3$ thermoelectric device loaded with the MA electrode. The MA electrode was mounted on the one end of the Bi$_{0.3}$Sb$_{1.7}$Te$_3$ element and a control electrode was attached on the other end of the element. (B) Experimental setup for thermoelectric measurements. (C) Schematic of the MA thermoelectric device and two thermistors capped with a carbon pod. (D) Dependence of the output voltages generated on the MA device (red) and a control device (black) on the measured environment temperatures. (E) Correlation between the local heat temperatures generated on the MA-Bi$_{0.3}$Sb$_{1.7}$Te$_3$ thermoelectric device and the calculated power density absorbed by the MA.

These results indicate the mechanism of metamaterial thermoelectric voltage generation in a uniform temperature environment. MA absorbs thermal radiation emitted from the surrounding environment and generates local heating as a consequence of absorption losses by the MA. The local heat propagates to the Bi$_{0.3}$Sb$_{1.7}$Te$_3$ thermoelectric device via a copper electrode, resulting in an additional thermal gradient across the Bi$_{0.3}$Sb$_{1.7}$Te$_3$ device and subsequent output voltage generation.

To ascertain our understanding of the driving mechanism of metamaterial thermoelectric conversion, we calculated the local heat temperatures generated on the MA using the finite element method, COMSOL Multiphysics software. The calculation was performed at an environmental temperature of 364 K, which was the measured temperature obtained at an electric furnace temperature setting of 373 K. As we reported the details of the calculation in (2), we showed the results of the calculated local heat temperature and discussed the effect of radiative cooling here (see Supplementary Text for details).
We considered the radiative cooling effect of the MA in these calculations, since a good absorber is a good emitter according to Kirchhoff’s law (18-20). We calculated the local heat temperature using a heat transfer equation that involved the radiative heat flux term $Q_{rad}(r)$. This equation means that some of the energies absorbed by the MA will be lost as radiative heat flux. The radiative heat flux can be represented using the Stefan–Boltzmann equation (Eq. (S3)), indicating that the amount of radiative heat flux depends on the temperature difference between the MA and surrounding medium. We concluded that the radiative heat fluxes certainly exist in our system; however, its effect is negligible because of two reasons. First, radiative cooling will occur at an atmospheric window of 8–13 µm, which is outside of the MA resonance utilized in this study. Second, our experiments were conducted in a closed carbon pod placed in a furnace. The walls of the carbon pod and furnace obstruct the radiation cooling. In our case, the radiative heat flux emitted from the MA surface is given to the air in the vicinity of the MA electrode. The temperatures of the MA electrode and surrounding air are approximately the same, resulting in a slight radiation heat flux according to Eq. (S3). In contrast, the absorbed energy of the MA is converted into local heating, leading to effective conductive heat propagation to the copper electrode owing to its high thermal conductivity, which results in an additional thermal gradient across the Bi$_{0.3}$Sb$_{1.7}$Te$_3$ thermoelectric device.

To estimate the local heat temperature, we obtained the dependence of the local temperatures on the number of units of the MA and control models (Figure S4), and the logarithmic fit to the calculated data as per Eqs. (1) and (2). We have previously reported obtaining these equations in (16).

$$T_{MA} = 0.0056 \ln(x) + 0.0822 \quad \text{Eq. (1)},$$

$$T_{control} = 0.0007 \ln(x) + 0.0111 \quad \text{Eq. (2)}.$$  

As there are 490,000 units of the MA in the fabricated area (2.1 × 2.1 mm$^2$), the calculated local heat temperature of 0.16 K was obtained, which is of a comparable level to the additional temperature gradient estimated by the output voltage generated at the environment temperature of 364 K. In contrast, heat generation corresponding to the temperature of 0.02 K was observed on the surface of the control electrode, which originated from the slight heat absorption of the CaF$_2$ and Ag layers deposited on the copper electrode (Figure 1(C) dashed line). The calculated local heat temperature generated on the MA electrode also supports our hypothesis that the output voltage generation under a uniform temperature environment is attributed to the thermal radiation absorption by the MA.

We also estimated the local temperatures generated by the thermal radiation absorption of the bare copper (the rear side of the electrodes) and Bi$_{0.3}$Sb$_{1.7}$Te$_3$ elements. Figure S5(A), and (B) show the measured and calculated absorption spectra of the copper and Bi$_{0.3}$Sb$_{1.7}$Te$_3$ elements. The copper element showed a slight absorption in the range of 2–25 µm, while the Bi$_{0.3}$Sb$_{1.7}$Te$_3$ element exhibited a broad absorption. There is a large difference between the measured and calculated absorption spectra of the Bi$_{0.3}$Sb$_{1.7}$Te$_3$ element because we considered bismuth telluride (Bi$_2$Te$_3$) material properties to estimate the absorption spectrum of the Bi$_{0.3}$Sb$_{1.7}$Te$_3$. Furthermore, we believe that the surface roughness of the Bi$_{0.3}$Sb$_{1.7}$Te$_3$ element might enhance its apparent absorption. However, we considered that these discrepancies between the measured and calculated absorption spectra are not critical for considering the metamaterial thermoelectric mechanism, as described later.
We obtained the dependence of the local temperature on the number of units (Eqs. (S4, 5)) to evaluate the local temperatures generated on bare copper and Bi$_{0.3}$Sb$_{1.7}$Te$_3$. As the measured Bi$_{0.3}$Sb$_{1.7}$Te$_3$ showed a considerable absorption in the IR region, we created a Bi$_{0.3}$Sb$_{1.7}$Te$_3$ model with a material depth of 500 µm which is a half-depth of the device element to estimate local temperature generated on the element. Table 1 presents the calculated local temperatures generated at each element of the MA thermoelectric device. The calculated local temperature generated on the MA was 0.16 K, which is much larger than that generated on the control electrode. Furthermore, the MA electrode and both Bi$_{0.3}$Sb$_{1.7}$Te$_3$ elements showed negligible temperatures, even though the Bi$_{0.3}$Sb$_{1.7}$Te$_3$ element showed higher absorptivity. The reason that the Bi$_{0.3}$Sb$_{1.7}$Te$_3$ element shows a negligible temperature is its low heat power density as we described later. However, we considered that the local temperatures generated on the Bi$_{0.3}$Sb$_{1.7}$Te$_3$ element would not affect the thermoelectric performance of the MA device for the following reasons. The Bi$_{0.3}$Sb$_{1.7}$Te$_3$ thermoelectric element has an isotropic shape, meaning that the thermal radiation absorption of the Bi$_{0.3}$Sb$_{1.7}$Te$_3$ does not induce temperature gradients across the element owing to uniform local heat generation across the element. On the other hand, the local heat generated on the MA electrode creates an anisotropic thermal distribution across the thermoelectric device. This means that the local heat generated on the MA electrode is the key to determining the output voltage across the device, regardless of the amount of temperature generated on the Bi$_{0.3}$Sb$_{1.7}$Te$_3$ thermoelectric element. As a proof of this concept, we carried out a thermoelectric simulation using COMSOL software.

**Table 1.** Calculated local temperatures at each element consisting of the MA thermoelectric device.

<table>
<thead>
<tr>
<th>Element</th>
<th>Calculated local temperature (K)</th>
</tr>
</thead>
<tbody>
<tr>
<td>MA</td>
<td>0.16</td>
</tr>
<tr>
<td>MA electrode (except MA area, with 60 nm-thick-CaF$_2$ and 150 nm-thick-Ag layers), and Control electrode (with 60 nm-thick-CaF$_2$ and 150 nm-thick-Ag layers)</td>
<td>0.02</td>
</tr>
<tr>
<td>Bare copper (Rear side of an electrode)</td>
<td>negligible</td>
</tr>
<tr>
<td>Bi$<em>{0.3}$Sb$</em>{1.7}$Te$_3$</td>
<td>negligible</td>
</tr>
</tbody>
</table>

In the thermoelectric simulation, the calculated power density, which corresponds to the electromagnetic energy density absorbed by the material, is injected into each element every second to simulate the thermal distribution across the MA thermoelectric device by considering local heat generation at each material. The power density is the total energy absorbed by the material over given area and can be expressed in units of W/m$^3$. These settings are required because all materials consisting of the device generate local heat depending on its absorption properties. This means that the thermal distribution across the thermoelectric device was formed depending
on the local heat temperatures generated on each element. The initial temperature of the thermoelectric simulation was 364.15 K, which is equal to the measured environmental temperature. In the simulation model, the metamaterial thermoelectric device was surrounded by an airbox with a size of $2.5 \times 2.5 \times 1.5 \text{ cm}^3$, which corresponded to the air space inside the carbon pod. Furthermore, to allow heat transfer from the inside of the airbox to the outside, a larger airbox with a size of $50 \times 50 \times 50 \text{ cm}^3$ was placed to cover the inner airbox.

Figure 3(A) and (B) present temperature and electric potential distributions across the MA thermoelectric device and control device calculated at 180 min. Position $X = 0 \text{ mm}$ corresponds to the MA electrode surface of the MA device or a left-side electrode surface of the control electrode. The area (i), (ii), and (iii) corresponds to the MA or a left-side electrode, the $\text{Bi}_{0.3}\text{Sb}_{1.7}\text{Te}_3$ element, and the opposite electrode, respectively. The thermal distribution of the MA device in Figure 3(A) showed an obvious temperature gradient from the MA electrode to the opposite electrode and showed a temperature difference of 0.14 K between the electrode surfaces, which shows a good agreement with the temperature difference obtained by experiments, 0.14 K. In contrast, the control device showed a flat temperature distribution over the whole device, indicating that a temperature gradient has not been induced.

The calculated electric potential distributions across the MA thermoelectric device shown in Figure 3(B) showed a potential difference of 20.0 $\mu$V, which is comparable to the output voltage experimentally obtained at an environmental temperature of 364 K. Meanwhile, the control electrode did not show a potential difference between the electrodes.

Figure 3(C) presents the time dependence of the potential differences between points a and b (Figure 3(C), upper inset) of the MA thermoelectric device and the control device. A potential difference of 20 $\mu$V in the MA thermoelectric was observed at 180 min. In contrast, the potential difference observed for the control device is almost negligible, approximately 2.0 nV. Thermoelectric simulation supports our hypothesis that the MA triggers the generation of a thermal gradient across the thermoelectric device placed in uniform temperature air.
Fig. 3 (A) Temperature and (B) electric potential distributions of the MA device (red line) and the control device (dashed black line) calculated at 180 min. The area (i), (ii), and (iii) corresponds to the MA electrode, the Bi$_{0.5}$Sb$_{1.7}$Te$_3$ element, and the opposite electrode, respectively. (C) Calculated time dependence of the potential differences between points a and b (the upper inset) of the MA device (red line) and a control device (dashed black line). Point a is close to the MA electrode for the MA device. The right lower inset is an enlarged potential difference graph of the control device.

Finally, we examined the output power of the $\pi$-type thermoelectric device loaded with the MA electrode. The n-type Bi$_2$Te$_3$ (provided by TOSHIMA Manufacturing Co. Ltd.) and a p-type Bi$_{0.5}$Sb$_{1.7}$Te$_3$ element were attached to the MA electrode by soldering paste. The control electrodes were attached to opposite edges of these elements. The output voltage generated on this $\pi$-type MA thermoelectric device was 98 $\mu$V at the measured environmental temperature of 364 K, corresponding to an output power of 0.04 $\mu$W/cm$^2$, 0.4 mW/m$^2$. This power density is currently small; however, there is much space to enhance this power density by utilizing broadband metamaterials (21-24). Metamaterial thermoelectric conversion can enhance the thermoelectric performance by increasing the thermal gradient across a thermoelectric device by up to 14% in an environment of 364 K, meaning that metamaterials can enhance the performance of conventional thermoelectric devices installed in a conventional site where a thermal gradient is maintained. Metamaterial thermoelectric conversion can give an equal impact to enhance the Seebeck coefficient of a thermoelectric material by 14%. It should be noted that the metamaterial thermoelectric conversion cannot drive under uniform temperature environments without thermal radiation, such as space. However, it can be adopted in uniform temperature environments such as hot water, asphalt roads, and furnaces where conventional thermoelectric devices are inapplicable.
In this research, we induced a thermal gradient across a thermoelectric element through the absorptivity control of both electrodes. The unbalanced absorptivity difference between the electrodes produced by metamaterials can design a thermal distribution across a certain object or space. This technique is one of the thermal engineering techniques and can be applied to control thermal distributions in microfluidics, electric circuits, and containers that are filled with medium (25-27).

References and Notes:
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Supplementary Materials:
Materials and Methods
Figures S1-S5
Supplementary Materials for

Metamaterial Thermoelectric Conversion

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Materials and Methods

Fabrication of metamaterial absorber (MA)

A 300 µm-thick copper plate with a size of 4 × 6 mm was thoroughly washed with acetone and pure water with sonication. A 150 nm-thick silver (Ag) layer and a 60 nm-thick calcium fluoride (CaF$_2$) layer were deposited on the copper plate using a thermal evaporator (SVC-7TS, Sanyu Electron Corporation).

To fabricate the MA arrays, hole patterns were drawn on a positive resist layer (ZEP520A, ZEON CORPORATION) formed on the CaF$_2$ and Ag layers deposited on a copper plate using electron beam lithography (JBX-6300FS, JEOL Ltd.), followed by development. An Ag layer with a thickness of 100 nm was deposited on the patterned resist layer by thermal deposition. Ag disk arrays were obtained after the lift-off process (Figure 1(B)).

Preparation of the metamaterial thermoelectric device and a control device

The MA-fabricated-Cu electrode was attached to the edge of a Bi$_{0.3}$Sb$_{1.7}$Te$_3$ thermoelectric element by soldering paste. Bi$_{0.3}$Sb$_{1.7}$Te$_3$ thermoelectric elements with a cross-sectional area and a length of 1 × 2 mm$^2$ and 8.8 mm, respectively, were provided by TOSHIMA Manufacturing Co., Ltd. A control electrode was attached to the other edge of the thermoelectric element.

Optical characteristics measurement of metamaterial absorber

The reflection spectra of the MA arrays, fabricated on a copper electrode, were measured by microscopic Fourier transform infrared spectroscopy (FT/IR-6300, VIRT-3000, JASCO Corporation). The reference spectrum was recorded on a bare copper plate in the vicinity of the MA pattern. For the reflection spectrum of a bare copper surface, a 150 nm-thick Ag layer deposited on bare copper was used as a reference.

Seebeck coefficient measurement

A control device loaded with control electrodes was used to measure the Seebeck coefficient of the p-type Bi$_{0.3}$Sb$_{1.7}$Te$_3$ thermoelectric element. One edge of the device was attached to the surface of a hotplate. The temperature at the rear of the electrodes was monitored by thermistors, and the voltage was measured using a multimeter (DMM-6500, Keithley Instrument).

Thermoelectric measurement

An electric furnace (FUL210FA, ADVANTEC) was used as a heater to create a uniform temperature environment. The Bi$_{0.3}$Sb$_{1.7}$Te$_3$ thermoelectric device capped with a carbon pod with a diameter and a height of 2.5 and 1.5 mm, respectively, was put on a plastic board placed at the middle of the furnace chamber. Two thermistors were placed 2 mm away from the electrode surfaces of the thermoelectric device to monitor the environmental temperatures in the vicinity of the electrodes (see Figure 2(C)). The entire device was placed on a universal substrate located in the middle of the furnace chamber and capped with a carbon pod. We made the base of both electrodes contact with the universal substrate carefully since inhomogeneous contact between the electrode and substrate will affect the thermoelectric performance. The carbon pod plays a role in
eliminating the convection effect on thermoelectric performance. During heating, the electric furnace door was closed, and heating was carried out in a closed chamber.

The output voltage generated on the thermoelectric device was measured using a multimeter. The temperatures in the vicinity of the electrodes of the thermoelectric device were monitored by thermistors (see “Thermistor calibration” for details).

**Thermistor calibration**

A thermistor probe (Micro-BetaCHIP thermistor probe, Measurement Specialties, Inc.) was used to measure the environmental temperature. The thermistor is a negative temperature coefficient (NTC) type and has a probe head with a length and a diameter of 3.3 and 0.3 mm, respectively. The thermistor was connected to a temperature sensing circuit that produced an output voltage linear to the environmental temperature.

We utilized the calibrated B values of the thermistor to estimate the environmental temperatures. The B value is an indication of a graph curve that represents the relationship between the resistance and temperature of the thermistor. We measured the resistance of the thermistors at 298 and 353 K to calculate the intrinsic B value for each thermistor. The B values for thermistors 1 (left side) and 2 (right side) were 4288 and 4277, respectively. We placed thermistors 1 and 2 close together at the same position to be exposed to the same temperature in a uniform temperature environment and calculated the temperature difference between the two thermistors after the environment temperature reached an equilibrium. Figure S1 presents the dependence of the temperature differences between the two thermistors on the environmental setting temperatures. The temperature differences between the two thermistors were in the range of ± 0.2 K at every setting temperature, indicating that the thermistors showed a maximum temperature difference of ± 0.2 K at maximum even though the thermistors have the same temperature. Based on these experiments, we concluded that the environmental temperature measured by the left and right thermistors is the same if the temperature difference between the two thermistors is less than ± 0.2 K.
**Fig. S1.** Dependence of the differential temperature between the left and right thermistors on the setting temperatures of an electric furnace. The circle plots present the temperature differences between the left and right thermistors calculated by the calibrated (red) and the catalog (black) B values.

**Numerical calculation to estimate local heat temperature**

COMSOL Multiphysics software was used to calculate local heat temperature. The calculations were performed at an environmental temperature of 364 K. The calculation details are reported in (1). The absorbed energies of the MA, corresponding to the heat power density $Q(r)$, can be calculated using the electric field intensity, as described in Eq. (1).

$$ Q(r) = \frac{\omega}{2} \text{Im}(\varepsilon(\omega))\varepsilon_0 |E(r)|^2, \quad (S1) $$

where $\text{Im}$ is the imaginary part, $\varepsilon(\omega)$ is the relative permittivity of the material, $\varepsilon_0$ is the vacuum permittivity, and $|E(r)|^2$ is the intensity of the electric field. The local heating can be calculated using Eq. (2) by considering the radiative cooling effect.

$$ \rho(r)c(r) \frac{\delta T(r)}{\delta t} = \nabla \kappa(r) \nabla T(r) + Q(r) + Q_{rad}(r), \quad (S2) $$

where $\rho(r)$ is the mass density, $c(r)$ is the specific heat, and $T(r)$ is the temperature. $\nabla \kappa(r) \nabla T(r)$ represents the conductive heat flux, and $Q_{rad}(r)$ is the radiative heat flux described by Eq. (S3).

$$ Q_{rad}(r) = \varepsilon \sigma A(T(r) - T_{\text{surr}})^4, \quad (S3) $$

where $\varepsilon$ is the emissivity, $\sigma$ is the Stefan–Boltzmann constant, $A$ is the area of the absorber, $T(r)$ is the surface temperature of the MA, and $T_{\text{surr}}$ is the surrounding environmental temperature.
Eq. (2) involves $Q_{\text{rad}}(\mathbf{r})$ to consider the radiative cooling effect of the MA, as a good absorber is a good emitter according to Kirchhoff’s law.

To consider the total power density of the $\text{Bi}_{0.3}\text{Sb}_{1.7}\text{Te}_3$ element, whose volume is much larger than that of the MA, we created a model with a material depth of 500 $\mu$m for the $\text{Bi}_{0.3}\text{Sb}_{1.7}\text{Te}_3$ element. This depth corresponded to the half-length of the $\text{Bi}_{0.3}\text{Sb}_{1.7}\text{Te}_3$ element. A calculation model involving bulk would provide a more accurate power density (W/m$^3$), leading to an estimation of local heating close to the measured temperature values.

**Fig. S2.** Time dependence of the output voltage generated across the MA thermoelectric device. The red line presents time dependence of the output voltage generated on the MA device, and the dashed lines present the environmental temperatures at the left electrode (dashed black) and at the right electrode (dashed blue) measured by the left and right thermistors. Electric furnace heating with a set temperature of 373 K was started at 0 sec, and was kept till the set temperature was achieved at 18500 sec. At 18500 sec, electric furnace heating was stopped.
**Fig. S3.** Comparison of the measured absorption spectrum of the MA (black line) and the calculated blackbody radiation spectra at 320 (48 °C, dark blue), 342 (70 °C, blue), 364 (91 °C, light blue), 388 (118 °C, purple), and 402 K (130 °C, red).

**Fig. S4.** Dependence of the local temperatures on the number of the units in an array. Calculated local heating temperatures as a function of the number of the MA (red) and control (black) units. The dashed lines indicate logarithmic fits to the data.
**Fig. S5.** Measured (solid lines) and calculated (dashed lines) absorption spectra of (A) a bare copper and (B) Bi$_{0.3}$Sb$_{1.7}$Te$_3$ element. The blue lines in (a, b) show the blackbody radiation spectra at 364 K. (C) Dependence of the local temperatures on the number of the units in an array. Calculated local heating temperatures as a function of the number of the Bi$_{0.3}$Sb$_{1.7}$Te$_3$ (black circles) and a copper electrode (hollow circles) units. The dashed lines indicate logarithmic fits to the data.

\[ T_{\text{copper}} = 8 \times 10^{-5} \ln(x) + 0.00007 \quad \text{Eq. (S4)}, \]
\[ T_{\text{Bi}_{0.3}\text{Sb}_{1.7}\text{Te}_3} = 5 \times 10^{-9} \ln(x) + 0.0051 \quad \text{Eq. (S5)}. \]